



PJT7600

20V Complementary Enhancement Mode MOSFET – ESD Protected

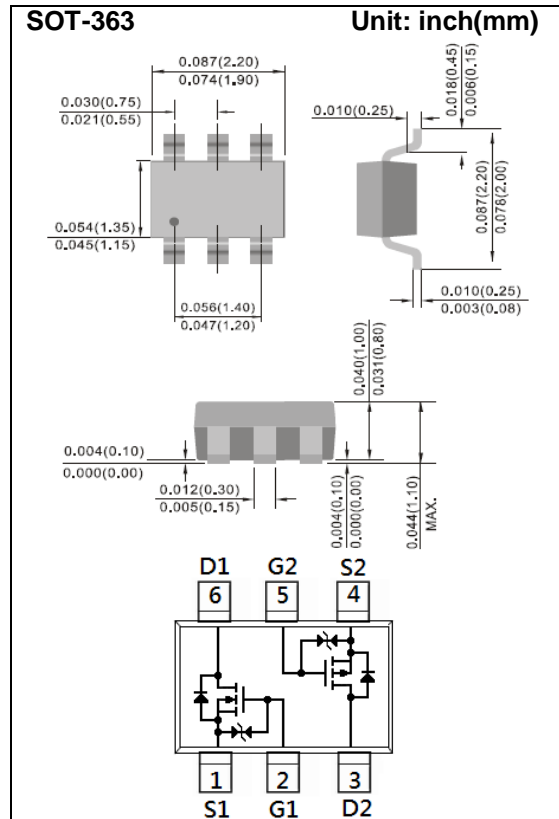
Voltage 20 / -20V **Current** 1 / -0.7A

Features

- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-363 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0002 ounces, 0.006 grams
- Marking: T60



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS
Drain-Source Voltage		V _{DS}	20	-20	V
Gate-Source Voltage		V _{GS}	±8	±8	V
Continuous Drain Current		I _D	1	-0.7	A
Pulsed Drain Current (Note 4)		I _{DM}	4	-2.8	A
Power Dissipation	T _a =25°C	P _D	350		mW
	Derate above 25°C		2.8		mW/°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55~150		°C
Typical Thermal resistance - Junction to Ambient (Note 3)		R _{θJA}	357		°C/W



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N-Channel Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	0.8	1.0	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=1A$	-	114	150	m Ω
		$V_{GS}=2.5V, I_D=0.7A$	-	160	215	
		$V_{GS}=1.8V, I_D=0.3A$	-	280	400	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$	-	0.01	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	-	± 2	± 10	μA
Dynamic						
Total Gate Charge	Q_g	$V_{DS}=10V, I_D=1A,$ $V_{GS}=4.5V$ (Note 1,2)	-	1.6	-	nC
Gate-Source Charge	Q_{gs}		-	0.3	-	
Gate-Drain Charge	Q_{gd}		-	0.41	-	
Input Capacitance	C_{iss}	$V_{DS}=10V, V_{GS}=0V,$ $f=1.0\text{MHz}$	-	92	-	pF
Output Capacitance	C_{oss}		-	25	-	
Reverse Transfer Capacitance	C_{rss}		-	9.1	-	
Switching						
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, I_D=1A,$ $V_{GS}=4.5V, R_G=6\Omega$ (Note 1,2)	-	5.8	-	ns
Turn-On Rise Time	t_r		-	25.7	-	
Turn-Off Delay Time	$t_{d(off)}$		-	41	-	
Turn-Off Fall Time	t_f		-	31	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	1	A
Diode Forward Voltage	V_{SD}	$I_S=1A, V_{GS}=0V$	-	0.85	1.2	V



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P-Channel Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.5	-0.64	-1	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-0.7A$	-	260	325	m Ω
		$V_{GS}=-2.5V, I_D=-0.6A$	-	310	420	
		$V_{GS}=-1.8V, I_D=-0.5A$	-	400	600	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-20V, V_{GS}=0V$	-	-0.01	-1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	-	± 3.5	± 10	μA
Dynamic						
Total Gate Charge	Q_g	$V_{DS}=-10V, I_D=-0.7A,$ $V_{GS}=-4.5V$ (Note 1,2)	-	2.2	-	nC
Gate-Source Charge	Q_{gs}		-	0.4	-	
Gate-Drain Charge	Q_{gd}		-	0.5	-	
Input Capacitance	C_{iss}	$V_{DS}=-10V, V_{GS}=0V,$ $f=1.0\text{MHZ}$	-	151	-	pF
Output Capacitance	C_{oss}		-	27	-	
Reverse Transfer Capacitance	C_{rss}		-	8.8	-	
Switching						
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-10V, I_D=-0.7A,$ $V_{GS}=-4.5V, R_G=6\Omega$ (Note 1,2)	-	2.2	-	ns
Turn-On Rise Time	t_r		-	19.2	-	
Turn-Off Delay Time	$t_{d(off)}$		-	6.2	-	
Turn-Off Fall Time	t_f		-	23	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	-1	A
Diode Forward Voltage	V_{SD}	$I_S=-1A, V_{GS}=0V$	-	-0.86	-1.2	V

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.



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N-Channel TYPICAL CHARACTERISTIC CURVES

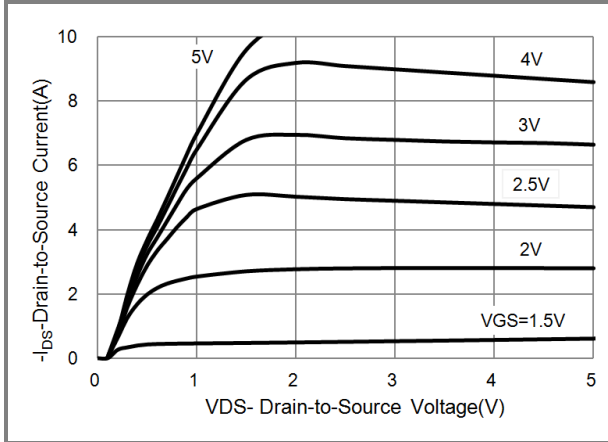


Fig.1 On-Region Characteristics

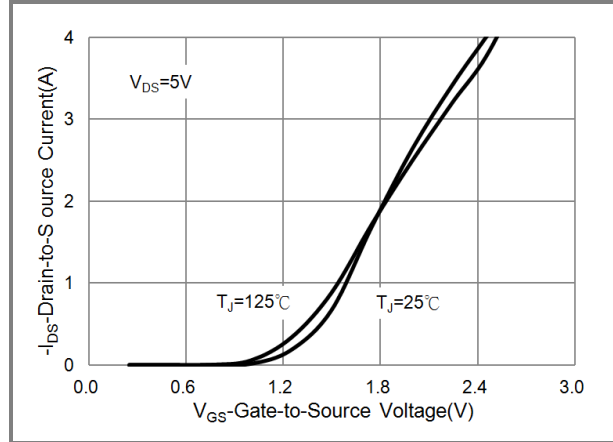


Fig.2 Transfer Characteristics

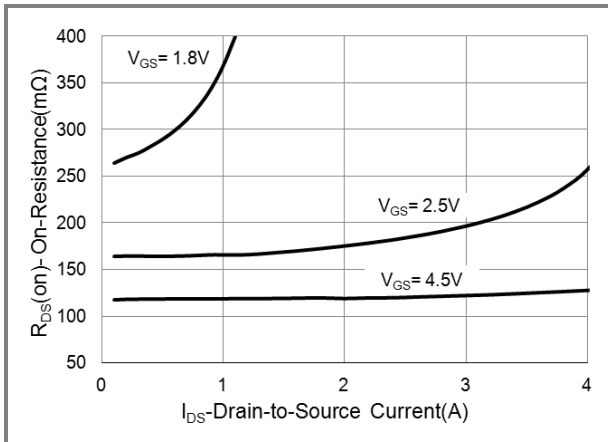


Fig.3 On-Resistance vs. Drain Current

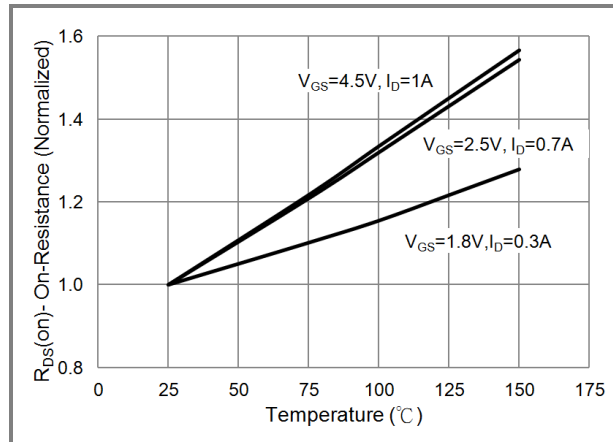


Fig.4 On-Resistance vs. Junction temperature

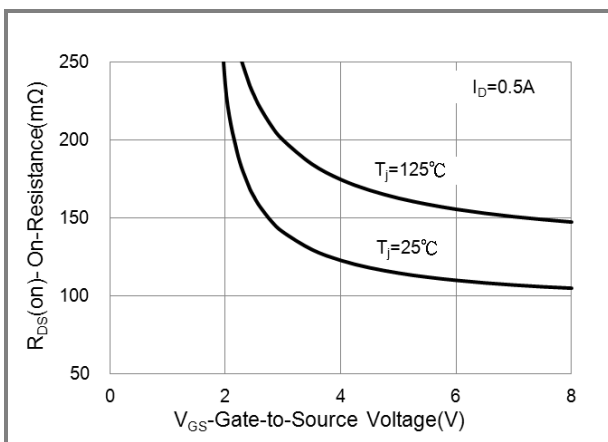


Fig.5 On-Resistance Variation with V_{GS} .

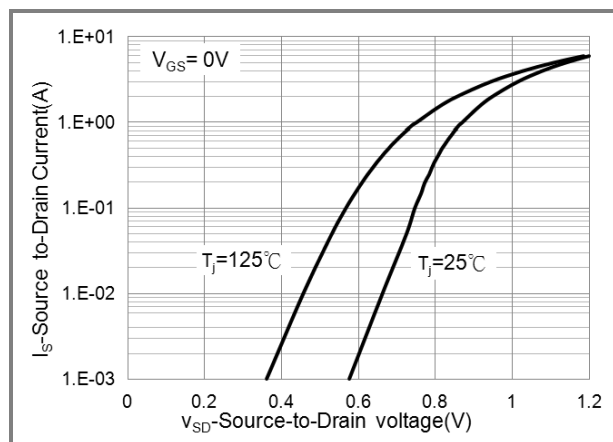


Fig.6 Body Diode Characteristic



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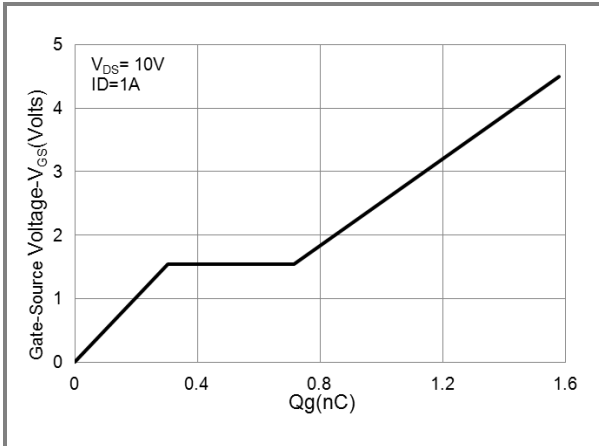


Fig.7 Gate-Charge Characteristics

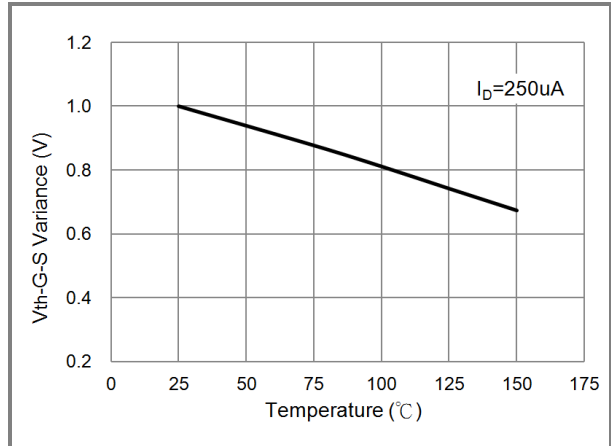


Fig.8 Threshold Voltage Variation with Temperature.

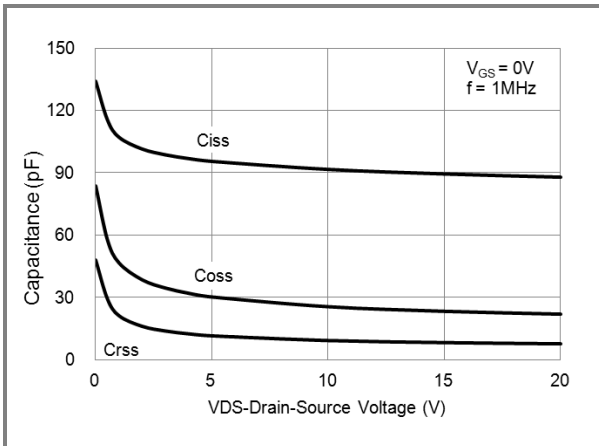


Fig.9 Capacitance vs. Drain-Source Voltage.



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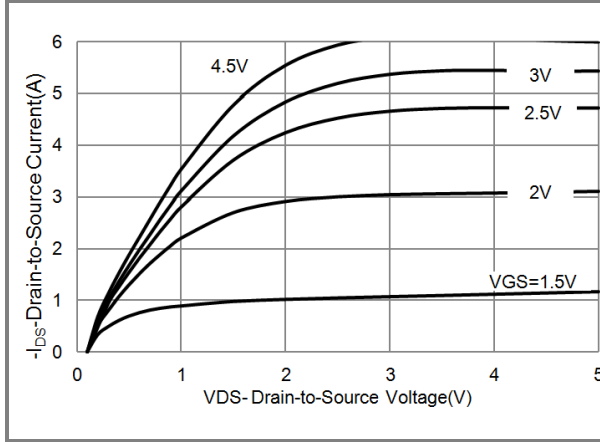


Fig.1 On-Region Characteristics

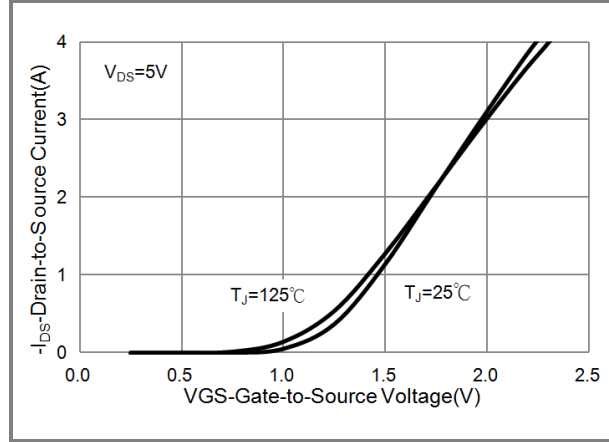


Fig.2 Transfer Characteristics

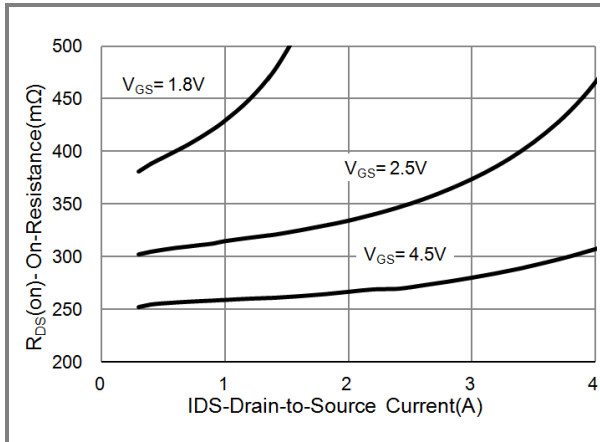


Fig.3 On-Resistance vs. Drain Current

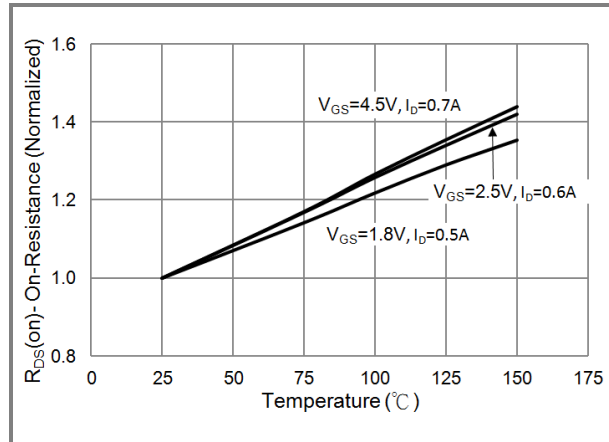


Fig.4 On-Resistance vs. Junction temperature

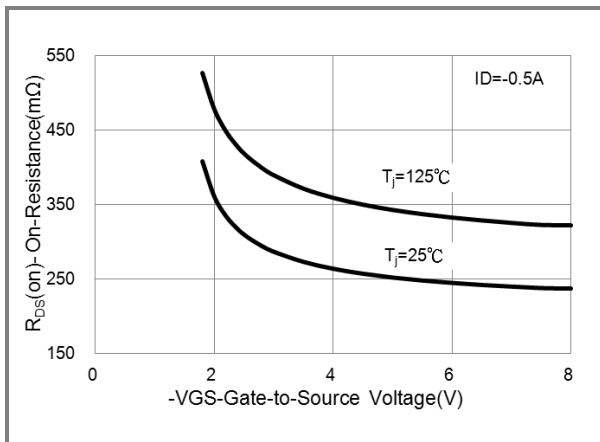


Fig.5 On-Resistance Variation with V_GS.

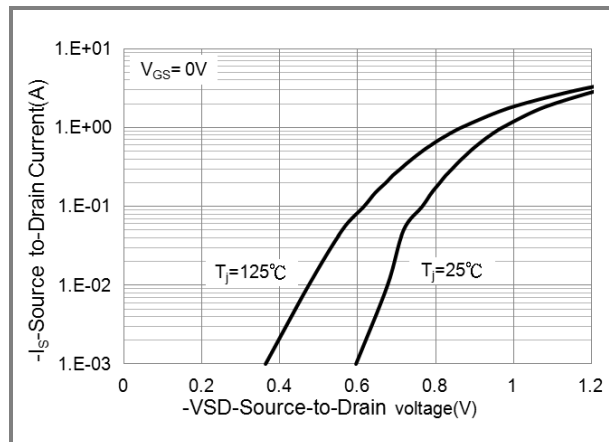


Fig.6 Body Diode Characteristics



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P-Channel TYPICAL CHARACTERISTIC CURVES

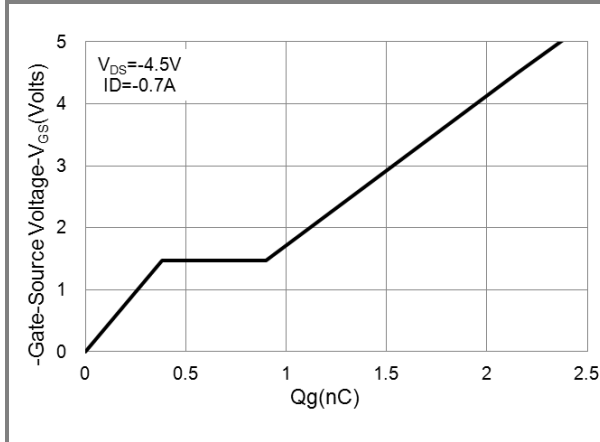


Fig.7 Gate-Charge Characteristics

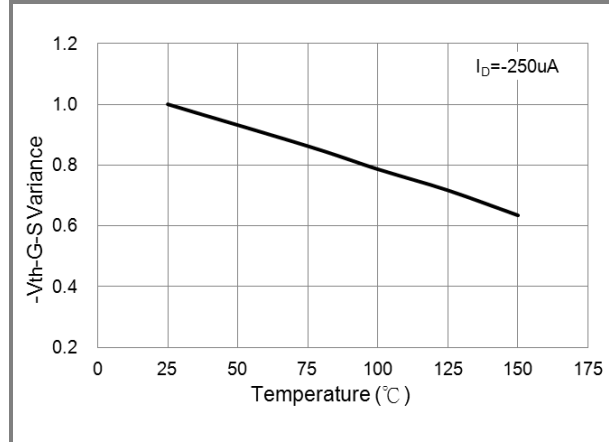


Fig.8 Threshold Voltage Variation with Temperature.

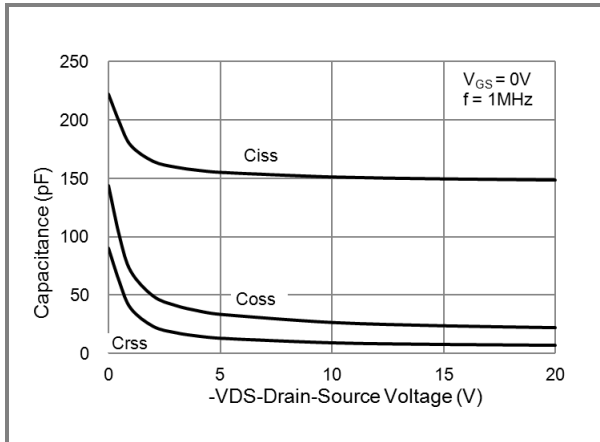


Fig.9 Threshold Voltage Variation with Temperature.

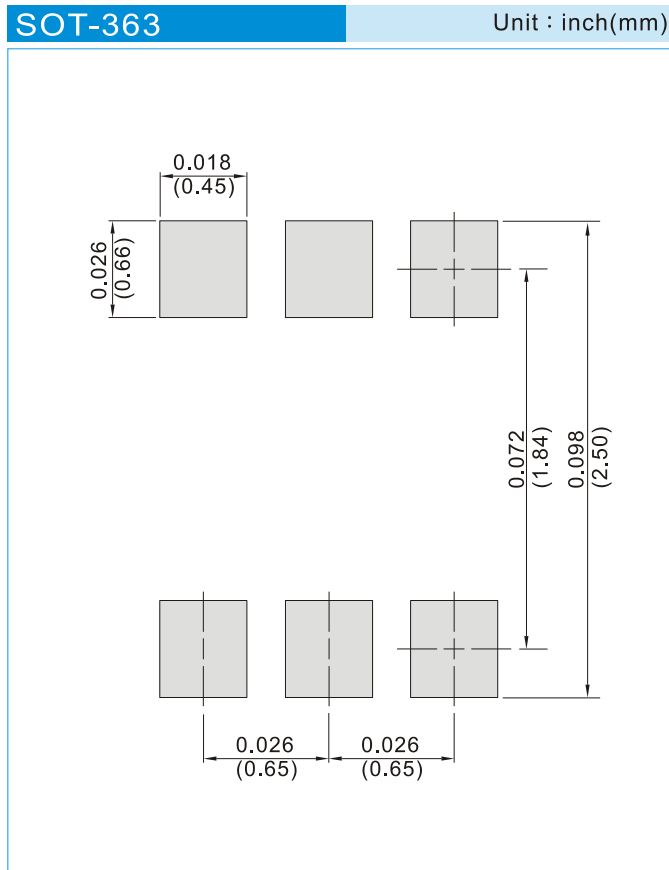


PJT7600

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJT7600_R1_00001	SOT-363	3K pcs / 7" reel	T60	Halogen free
PJT7600_R2_00001	SOT-363	10K pcs / 13" reel	T60	Halogen free

MOUNTING PAD LAYOUT





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